## ALTERNATION HISTORY RECORDS 变更记录

Т			I	SONDO 文文化水						
Date 日期	Version 版本	Mark 标记	Page 页码	Description 描述	Drafter 制定者	Approver 审批者				
2015-09-10	A	/	8	InitialIssue(首次发行)	汤勋	常斯琴				



## 1. FEATURES

- a. High Voltage in a given case size.
- b. High reliability and stability.
- c. RoHS Compliant

## 2. APPLICATIONS

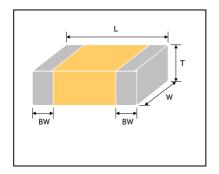
- a. DC to DC converter.
- b. High voltage coupling/DC blocking.
- c. Back-lighting inverters.
- d. Sunbbers in high frequency power convertors.

## 3.HOW TO ORDER

M	0 <u>80</u> 5	<u>B</u>	102	<u>K</u>	<u>101</u>	В	<u>D</u>
Туре	Size	Dielectric	Capacitance	Tolerance	Rated voltage	<u>Thickness</u>	<u>Packaging</u>
	Inch (mm) 0402 (1005) 0603 (1608) 0805 (2012) 1206 (3216) 1210 (3225) 1808 (4520) 1812 (4532) 1825 (4563) 2220 (5750) 2225 (5763)	N: COG(NPO) B: X7R Y: Y5V	Two significant digits followed by no. of zeros. And R is in place of decimal point.  eg.: R47=0.47pF 0R5=0.5pF 1R0=1.0pF 100=10x10° =10pF	B=±0.1pF C=±0.25pF D=±0.5pF F=±1% G=±2% J=±5% K=±10% M=±20% Z=-20/+80%	Two significant digits followed by no. of zeros. And R is in place of decimal point.  201= 200 VDC 251= 250 VDC 501= 500 VDC 631= 630 VDC	N: $0.50 \pm 0.05$ mm A: $0.60 \pm 0.10$ mm S: $0.80 \pm 0.10$ mm X: $0.80 \pm 0.20$ mm B: $0.85 \pm 0.15$ mm C: $0.95 \pm 0.10$ mm D: $1.25 \pm 0.10$ mm I: $1.25 \pm 0.20$ mm G: $1.60 \pm 0.20$ mm K: $2.00 \pm 0.20$ mm M: $2.50 \pm 0.30$ mm U: $2.80 \pm 0.30$ mm	K=0.5kpcs/ reel A=1kpcs/ reel B=2kpcs/ reel C=3kpcs/ reel D=4kpcs/ reel l=10kpcs/ reel



## 4. EXTERNAL DIMENSIONS



Size	L (mm)	W (mm)	Tmax (mm)	BW min (mm)	
0402 (1005)	1.00±0.05	0.50±0.05	0.55	0.15	
0603 (1608)	1.60±0.15	0.80±0.15	0.95	0.20	
0805 (2012)	2.00±0.20	1.25±0.20	1.45	0.30	
1204 (2214)	3.20±0.20	1.60±0.20	1.80	0.30	
1206 (3216)	3.20+0.3/-0.1	1.60+0.3/0.1	1.90	0.30	
1210 (3225)	3.20±0.40	2.50±0.30	2.80	0.30	
1808 (4520)	4.50±0.40	2.00±0.20	2.20	0.26	
1812 (4532)	4.50±0.40	3.20±0.30	2.80	0.26	
1825 (4563)	4.50±0.40	6.30±0.40	2.80	0.30	
2220 (5750)	5.70±0.40	5.00±0.40	3.10	0.30	
2225 (5763)	5.70±0.40	6.30±0.40	3.10	0.30	

## 5.GENERAL ELECTRICAL DATA

Dielectric	C0G(NPO)	X7R	Y5V					
Size	0402, 0603, 0805, 1206, 1210, 1808 ,1812	0603, 0805, 1206, 1210, 1808, 1812, 1825, 2220, 2225	0805, 1206, 1210, 1812					
Capacitance range*	0.5pF to 39.0nF	100pF to 1.0μF	10nF to 1.0μF					
Capacitance tolerance	Cap≤5pF: B (±0.1pF), C (±0.25pF)  5pF <cap<10pf: (±0.25pf),="" (±0.5pf)="" (±1%),="" (±10%)<="" (±2%),="" (±5%),="" c="" cap≥10pf:="" d="" f="" g="" j="" k="" th=""><th>J (±5%), K (±10%), M (±20%)</th><th>Z (-20/+80%)</th></cap<10pf:>	J (±5%), K (±10%), M (±20%)	Z (-20/+80%)					
Rated voltage (WVDC)	100V, 200V, 250V, 500V, 630V	100V, 200V,250V, 500V, 630V	100V, 200V, 250V					
Tan δ*	Cap<30pF: Q≥400+20C Cap≥30pF: Q≥1000	≤2.5% (Apply 1.0±0.2Vrms, 1.0KHz±10%)	≤5%					
Insulation resistance at Ur**	≥100GΩ or R•C≥1000 whichever is smaller	≥10GΩ or R•C≥100Ω-F which	hever is smaller					
Operating temperature	-55 to +1	25°C	-25 to +85°C					
Capacitance characteristic	±30ppm / °ℂ	±15%	+30/-80%					
Termination	Cu (or A	Cu (or Ag)/Ni/Sn (lead-free termination)						

<sup>\*</sup> Measured at the condition of 30~70% related humidity.

C0G(NPO): Apply 1.0±0.2Vrms, 1.0MHz±10% for Cap≤1000pF and 1.0±0.2Vrms, 1.0kHz±10% for Cap>1000pF, 25°C at ambient temperature X7R: Apply 1.0±0.2Vrms, 1.0kHz±10%, at 25°C ambient temperature.

Y5V: Apply 1.0±0.2Vrms, 1.0kHz±10%, at 20°C ambient temperature.

<sup>\*\*</sup>Measured at 500VDC for 60 sec, for  $U_R > 500VDC$ 



DIE	LECTRIC												NP0										
SIZ	Έ	04	02	06	03		08	05			12	06			12	10		18	808		18	12	
	TED LTAGE CD)	200	250	200	250	200	250	500	630	200	250	500	630	200	250	500	630	500	630	200	250	500	630
,	0.5pF(0R5)	N	N	S	S	Α	Α	Α	Α														
	1.0pF(1R0)	N	N	S	S	Α	Α	Α	Α														
	1.2pF (1R2)	Ν	Ν	S	S	Α	Α	Α	Α														
	1.5pF (1R5)	N	Ν	S	S	Α	Α	Α	Α	В	В	В	В										
	1.8pF (1R8)	N	N	S	S	Α	Α	Α	Α	В	В	В	В					D	D				
	2.2pF (2R2)	N	N	S	S	Α	Α	Α	Α	В	В	В	В					D	D				
	2.7pF (2R7)	N	N	S	S	Α	Α	Α	Α	В	В	В	В					D	D				
	3.3pF (3R3)	N	N	S	S	Α	Α	Α	Α	В	В	В	В					D	D				
	3.9pF (3R9	N	N	S	S	Α	Α	Α	Α	В	В	В	В					D	D				
	4.7pF (4R7)	N	N	S	S	Α	Α	Α	Α	В	В	В	В					D	D				
	5.6pF (5R6)	N	N	S	S	Α	A	A	Α	В	В	В	В					D	D				
	6.8pF (6R8)	N	N	S	S	A	Α	Α	A	В	В	В	В					D D	D D				-
	8.2pF (8R2)	N	N	S	S	Α	Α	Α	A	В	В	В	В	-	-	-	-				_	_	_
	10pF (100)	N N	N N	S	S	A	A	A	A	В	B B	ВВ	B B	С	С	С	С	D D	D D	D D	D D	D D	D D
	12pF (120) 15pF (150)	N	N	S	S	A	A	A	A	В	В	В	В	С	С	С	С	D	D	D	D	D	D
	18pF (180)	N	N	S	S	A	A	A	A	В	В	В	В	С	С	С	С	D	D	D	D	D	D
	20pF (200)	N	N	S	S	Α	Α	Α	Α	В	В	В	В	С	С	С	С	D	D	D	D	D	D
	22pF (220)	N	N	S	S	Α	Α	Α	Α	В	В	В	В	С	С	С	С	D	D	D	D	D	D
	27pF (270)	N	N	S	S	Α	Α	Α	Α	В	В	В	В	С	С	С	С	D	D	D	D	D	D
	33pF (330)	N	N	s	s	Α	Α	Α	Α	В	В	В	В	С	С	С	С	D	D	D	D	D	D
	39pF (390)	N	N	S	S	Α	Α	Α	Α	В	В	В	В	С	С	С	С	D	D	D	D	D	D
	47pF (470)	N	N	S	S	Α	Α	Α	Α	В	В	В	В	С	С	С	С	D	D	D	D	D	D
	56pF (560)	N	N	S	S	Α	Α	Α	Α	В	В	В	В	С	С	С	С	D	D	D	D	D	D
ø		N		S	S	Α	Α	Α	Α	В	В	В	В	С	С	С	С	D	D	D	D	D	D
apacitance	82pF (820)	N		S	S	Α	Α	Α	Α	В	В	В	В	С	С	С	С	D	D	D	D	D	D
ita	100pF (101)	Ν		S	S	Α	Α	Α	Α	В	В	В	В	С	С	С	С	D	D	D	D	D	D
ac	120pF (121)			S	S	Α	В	D	D	В	В	В	В	С	С	С	С	D	D	D	D	D	D
ap	150pF (151)			S	S	В	D	D	D	В	В	В	В	С	С	С	С	D	D	D	D	D	D
Ö	180pF (181)			S	S	В	D	D	D	В	В	В	В	С	С	С	С	D	D	D	D	D	D
	220pF (221)			S	S	D	D	D	D	В	В	В	В	С	С	С	С	D	D	D	D	D	D
	270pF (271)			Х	Х	D	D	D	D	В	С	С	С	С	С	С	С	K	K	D	D	D	D
	330pF (331)			Х	Х	D	D	D	D	В	С	С	С	С	С	С	С	K	K	D	D	D	D
	390pF (391)			Х	Х	D	D	D	D	В	С	С	С	С	С	С	С	K	K	D	D	D	D
	470pF (471)			X	X	D -	D	1	1	С	С	С	С	С	С	С	С	K	K	D -	D -	D -	D -
	560pF (561)			Х	Х	D	D			С	С	С	С	С	С	С	С	K	K	D	D	D	D
	680pF (681)					D	D	1	1	С	D	D	D	С	С	С	С	K	K	D	D	D	D
	820pF (821)					D D	D D	ı	l	С	D G	D G	D G	C D	C D	C D	C D	K	K	D D	D D	D D	D D
	1,000pF(102) 1,200pF (122)					D	D	-	<u> </u>	С	G	G	G	D	D	D	D	K	K	D	D	D	D
	1,200pF (122) 1,500pF (152)					D	D			D	G	G	G	D	D	D	D	K	K	D	D	D	D
	1,800pF (182)					D	D			D	G	G	G	D	D	D	D	K	K	D	D	D	D
	2,200pF (222)					D	D			D	G	G	G	D	D	D	D	K	K	D	D	D	D
	2,700pF (272									D	G			D	D	D	D			D	D	D	D
	3,300pF (332)									D	G			D	D	D	D			D	D	D	D
	3,900pF (392)									D	G			D	D	D	D			D	D	D	D
	4,700pF (472)									D	G			G	G					D	D	D	D
	5,600pF (562)													G	G					D	D	D	D
	6,800pF (682)													G	G					D	D	D	D
	8,200pF (822)													G	G							D	D
	0.010µF (103)													G	G							D	D
	0.022µF (223)													М	М							K	K
	0.033µF (333)													М	М							М	М



	SIZE TED VOLTAGE 100pF (101)		0603					_					X7F												
RAT	TED VOLTAGE				- 08	05				12	06					12	10			18	808		18	12	
-		200	250	200	250	500	630	200	250	400	450	500	630	200	250	400	450	500	630	500	630	200	250	500	630
-		X	X	В	В	В	В	D	D	400	430	D	D	D	D	400	430	D	D	300	030	200	230	300	030
  -  -	120pF (121)	Х	Х	В	В	В	В	D	D			D	D	D	D			D	D						
-	150pF (151)	Χ	Х	В	В	В	В	D	D			D	D	D	D			D	D	D	D				
	180pF (181)	Χ	Х	В	В	В	В	D	D			D	D	D	D			D	D	D	D				
_	220pF (221)	Χ	Х	В	В	В	В	D	D			D	D	D	D			D	D	D	D				
	270pF (271)	Χ	Χ	В	В	В	В	D	D			D	D	D	D			D	D	D	D				
-	330pF (331)	Χ	Х	В	В	В	В	D	D			D	D	D	D			D	D	D	D				
_	390pF (391)	Х	Х	В	В	В	В	D	D			D	D	D	D			D	D	D	D				
-	470pF (471)	X	X	В	В	В	В	D	D			D	D	D	D			D	D	D	D				
-	560pF (561) 680pF (681)	X	X	B B	В	B B	B B	D	D D			D D	D D	D	D C			D D	D D	D D	D				_
-	820pF (821)	X	X	В	B B	В	В	D D	D			D	D	С	С			D	D	D	D D				
	1,000pF (102)	X	X	В	В	В	В	D	D			D	D	С	С			D	D	D	D	D	D	D	D
I ⊨	1,200pF (122)	X	X	В	В	В	В	D	D			D	D	С	С			D	D	D	D	D	D	D	D
_	1,500pF (152)	X	X	В	В	В	В	D	D			D	D	С	С			D	D	D	D	D	D	D	D
- I	1,800pF (182)	X	X	В	В	В	В	D	D			D	D	С	С			D	D	D	D	D	D	D	D
I -	2,200pF (222)	Х	Х	В	В	В	В	D	D			D	D	С	С			D	D	D	D	D	D	D	D
_	2,700pF (272)	Х	Х	В	В	В	В	D	D			D	D	С	С	1		D	D	D	D	D	D	D	D
	3,300pF (332)	Χ	Χ	В	В	В	В	D	D			D	D	С	С			D	D	D	D	D	D	D	D
	3,900pF (392)	Χ	Х	В	В	В	В	D	D			D	D	С	С			D	D	D	D	D	D	D	D
	4,700pF (472)	Χ	Χ	В	В	D	D	D	D			D	D	С	С			D	D	D	D	D	D	D	D
ω _	5,600pF (562)	Χ	Χ	D	D	D	D	D	D			D	D	С	С			D	D	K	K	D	D	D	D
ů.	6,800pF (682)	Χ	Х	D	D	D	D	D	D			D	D	С	С			D	D	K	K	D	D	D	D
<del> </del> =	8,200pF (822)	Χ	Х	D	D	D	D	D	D			D	D	С	С			D	D	K	K	D	D	D	D
ac	0.010µF (103)	Х	Х	D	D	D	D	D	B/D			D	D	С	С			D	D	K	K	D	D	D	D
ă⊨	0.012µF (123)			D D	D	D D	D D	D D	D D			D D	D D	С	C			D D	D D	K	K	D D	D D	D D	D D
	0.015μF (153) 0.018μF (183)			D	D D	D	D	D	D			D	D	С	С			D	D	K	K	D	D	D	D
_	0.018µF (183) 0.022µF (223)			D	D	D	D	D	D			G	G	С	С			D	D	K	K	D	D	D	D
_	0.027µF (273)			D	D			D	D			G	G	С	С			G	G	K	K	D	D	D	D
_	0.033µF (333)			D	D			G	G			G	G	С	С			G	G	K	K	D	D	D	D
_	0.039µF (393)			D	D			G	G			G	G	С	С			G	G	K	K	D	D	D	D
	0.047µF (473)			D	D			G	G			G	G	D	D			G	G	K	K	D	D	D	D
	0.056µF (563)			D	D			G	G			G	G	D	D			G	G	K	K	D	D	K	K
	0.068µF (683)			D	D			G	G	G	G			G	G			K	K	K	K	D	D	K	K
	0.082µF (823)			D				G	G	G	G			G	G			K	K	K	K	D	D	K	K
-	0.10µF (104)			D				G	G	G	G			G	G			K	K			D	D	K	K
-	0.12µF (124)							G	G					G	G	M	M	M	M			D	D	M	M
-	0.15µF (154)							G G	G G					M	M	M M	M	М	М			K	K	M	M M
-	0.18µF (184) 0.22µF (224)							G	G					M	M M	M	M M					K	K	M	M
-	0.22μF (224) 0.27μF (274)							G	G					M	M	M	M					K	K	M	IVI
-	0.27µF (274)													M	M	M	M					K	K	M	$\vdash$
	0.39µF (394)													М	М	<u> </u>						K	K	М	
	0.47µF (474)													M	M							K	K	M	$\Box$
	0.56µF (564)													М	М	1						М	М		
	0.68µF (684)													М	М							М	М		
	0.84µF (844)																					М	М		
	1.0µF (105)																					М	М		



## 7.APPLICATION NOTES

#### STORAGE

To prevent the damage of solderability of terminations, the following storage conditions are recommended:

Indoors under  $5 \sim 40^{\circ}$ C and  $20\% \sim 70\%$  RH.

No harmful gases containing sulfuric acid, ammonia, hydrogen sulfide or chlorine.

Packaging should not be opened until the capacitors are required for use. If opened, the pack should be re-sealed as soon as is practicable. Taped product should be stored out of direct sunlight, which might promote deterioration in tape or adhesion performance. The capacitors should be used within 6 months and checked the solderability before use.

#### HANDLING

Chip capacitors are dense, hard, brittle, and abrasive materials. They are liable to suffer mechanical damage, in the form of cracks or chips. Chip Capacitors should be handled with care to avoid contamination or damage. To use vacuum or plastic tweezers to pick up or plastic tweezers is recommended for manual placement. Tape and reeled packages are suitable for automatic pick and placement machine.

#### **PREHEAT**

In order to minimize the risk of thermal shock during soldering, a carefully controlled preheat is required. The rate of preheat should not exceed  $4^{\circ}$ C per second and the final preheat temperature should be within  $100^{\circ}$ C of the soldering temperature for small chips such as 0402, 0603, 0805 and 1206, within  $50^{\circ}$ C of the soldering temperature for bigger chips such as 1210, 1808, 1812, 1825, 2220 and 2225, etc.

#### SOLDERING

Use middy activated rosin RA and RMA fluxes do not use activated flux. The amount of solder in each solder joint should be controlled to prevent the damage of chip capacitors caused by the stress between solder, chips, and substrate.

Hand soldering with temperature-controlled iron not exceeding 30 watts and diameter of tip less than 1.2 mm is recommended, tip of iron should not contact the ceramic body directly, and the temperature of iron should be set to not more than  $260^{\circ}$ C.

For bigger chips such as 1210, 1808, 1812, 2220 and 2225, etc. wave soldering and hand soldering are no recommended.

Refer IPC/JEDEC J-STD-020D Method recommended soldering profiles:

Reflow not sooner than 15 minutes and not longer than 4 hrs after removal from the temperature/humidity chamber, subject the sample to 3 cycle of the appropriate reflow conditions as defined as blow Table description.

Profile Feature	Pb-Free Assembly
Preheat/Soak	·
Temperature Min.(T <sub>smin</sub> )	150℃
Temperature Max.(T <sub>smax</sub> )	<b>200</b> ℃
Time( $t_s$ ) from ( $T_{smin}$ to $T_{smax}$ )	60 to 120 seconds
Ramp-up rate(T <sub>L</sub> to T <sub>p</sub> )	3°C/second max.
Liquidous temperature(T <sub>L</sub> )	217℃
Time(t <sub>L</sub> ) maintained above T <sub>L</sub>	60 to 150 seconds
	For user Tp must not exceed the
Peak package body temperature(T <sub>p</sub> )	Classification temp 260°C
l eak package body temperature(Tp)	For suppliers Tp must equal or exceed the
	Classification temp 260°C
Time $(T_p)^*$ within 5°C of the specified	30* second
classification temperature(T <sub>c</sub> )	30 Second
Ramp-down rate (T <sub>p</sub> to T <sub>L</sub> )	6°C/second max.
Time 25°C to peak temperature 260°C	8 minutes max.

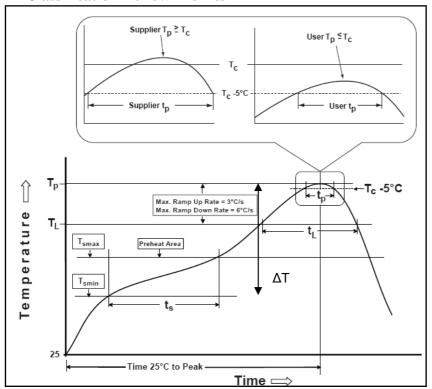


Lead-free : Soldering temperature = 235 to 260 $^{\circ}$ C, depending on product.

Maximum temperature = Minimum temperature (235°C)+ $\Delta$ T+ Tolerance for oven process and measurement(5 ~ 7°C)

Time at peak temperature = 10sec, Dwell above 217°C = 90sec, Ramping rate = 3°C/sec(heating) and 6°C/sec(heating).

#### **Classification Reflow Profiles**



Chip Size	ΔΤ
0402,0603,0805,1206	100 ℃
1210, 1808, 1812, 2211, 2220, 2225	50 ℃

Soldering	Solder Temp.(T <sub>c</sub> )	Soldering Time (t <sub>p</sub> )				
Reflow	235 − 260 °C	< 15 sec.				
Wave	230 − 260 °C	< 5 sec.				

Note : For example ,  $T_c$  is 260°C and time to is 15sec.

#### COOLING

After soldering, cool the chips and the substrate gradually to room temperature. Natural cooling in air is recommended to minimize stress in the solder joint. A cooling rate not exceeding 4°C per second should be used when forced cooling is necessary.

### **CLEANING**

All flux residues must be removed by using suitable electronic-grade vapor-cleaning solvents to eliminate contamination that could cause electrolytic surface corrosion. Good results can be obtained by using ultrasonic cleaning of the solvent. The choice of the proper system is depends upon many factors such as component mix, flux, and solder paste and assembly method. The ability of the cleaning system to remove flux residues and contamination from under the chips is very important.



# Approval sheet Medium Voltage Series 8.RELIABILITY TEST CONDITIONS AND REQUIREMENTS

		EITT TEST CONDITIONS AND	
No.	Item	Test Condition	Requirements
1.	Visual and		* No remarkable defect.
	Dimensions		* Dimensions to confirm to individual specification sheet.
	Capacitance	Class I: C0G(NP0)	* Shall not exceed the limits given in the detailed spec.
3.	Q/ D.F.	Cap≤1000pF, 1.0±0.2Vrms, 1MHz±10%	C0G(NPO): Cap≥30pF, Q≥1000; Cap<30pF, Q≥400+20C
	(Dissipation	Cap>1000pF, 1.0±0.2Vrms, 1KHz±10%	X7R: ≤2.5%
	Factor)	Class II: (X7R, Y5V)	Y5V: ≤5.0%
		1.0±0.2Vrms, 1kHz±10%	
4.	Temperature	With no electrical load.	
	Coefficient	T.C. Operating Temp	T.C. Capacitance Change
		C0G(NPO) -55~125°C at 25°C	C0G(NPO) Within ±30ppm/°C
		X7R -55~125°C at 25°C	X7R Within ±15%
		Y5V -25~85°C at 20°C	Y5V   Within +30%/-80%
5.	Insulation	U <sub>R</sub> =100V: To apply voltage at U <sub>R</sub> for max. 120 sec.	≥10GΩ or RxC≥100Ω-F whichever is smaller.
	Resistance	U <sub>R</sub> >100V: To apply voltage at U <sub>R</sub> (500V max.) for 60	
		sec.	
6.	Dielectric	* To apply voltage:	* No evidence of damage or flashover during test.
	Strength	100V =2.5 times of U <sub>R</sub>	
		200V/250V =2 times of U <sub>R</sub>	
		500V/630V =1.5 times of U <sub>R</sub>	
		* Duration: 1 to 5 sec.	
7.	Solderability	* Solder temperature: 235±5°C	95% min. coverage of all metalized area.
		* Dipping time: 2±0.5 sec.	
8.	Resistance	* Solder temperature: 260±5°C	* No remarkable damage.
	to Soldering Heat	* Dipping time: 10±1 sec  * Preheating: 120 to 150°C for 1 minute before	* Cap change: COG(NPO): within ±2.5% or ±0.25pF whichever is larger.
	Ticat	immerse the capacitor in a eutectic solder.	X7R: within ±7.5%
		* Before initial measurement (Class II only): Perform	Y5V: within ±20%
		150+0/-10°C for 1 hr and then set for 48±4 hrs at	* Q/D.F.:
		room temp.  * Measurement to be made after keeping at room	C0G(NPO) / X7R / Y5V : ≤ 1.0 × Initial requirement
		temp. for 24±2 hrs (Class I) or 48±4 hrs (Class II).	* 250/ many locabing on each odge
			* 25% max. leaching on each edge.
9.	Temperature	* Conduct the five cycles according to the	* No remarkable damage.
	Cycle	temperatures and time.	* Cap change :
		Step Temp. (°C) Time (min.)	COG(NPO): within ±2.5% or ±0.25pF whichever is larger.
		1 Min. operating temp. +0/-3 30±3	X7R: within ±7.5% Y5V: within ±20%
		2 Room temp. 2~3 3 Max. operating temp. +3/-0 30±3	* Q/D.F.:
		4 Room temp. 2~3	Q/D.F COG(NPO) / X7R / Y5V : ≤ 1.0 × Initial requirement
		* Before initial measurement (Class II only): Perform	* I.R. ≥ 0.25 × initial requirements.
		150+0/-10°C for 1 hr and then set for 48±4 hrs at	A.A. = 0.25 A milital requirements.
		room temp.	
		* Measurement to be made after keeping at room temp. for 24±2 hrs (Class I) or 48±4 hrs (Class II).	
10.	Humidity	* Test temp.: 40±2°C	
	(Damp Heat)	* Humidity: 90~95%RH	
	Load	* Test time: 500+24/-0 hrs.	* No remarkable damage.
		* To apply voltage: rated voltage (Max. 500V)	* Cap change: NP0: within ±7.5% or ±0.75pF whichever is larger.
		* Measurement to be made after keeping at room	X7R: within ±12.5%
		temp. for 24±2 hrs. (Class I) or 48±4 hrs. (Class II).	Y5V: within ±30%
			* Q/D.F. value:
			NP0: Cap≥30pF, Q≥200; Cap<30pF, Q≥100+10/3C
			X7R: ≤3.0%
			Y5V: ≤7.5% * LB: >500MO or ByC>250 E whichough is smaller
			* I.R.: ≥500MΩ or RxC≥25Ω-F whichever is smaller.
	•	•	



No.	Item	Test Condition	Requirements
11.	High Temperature Load (Endurance)	* Test temp.:  C0G(NPO), X7R: 125±3°C  Y5V: 85±3°C  * To apply voltage:  (1) U <sub>R</sub> ≤ 250V: 200% of rated voltage.  Exception item:	* No remarkable damage.
		UR     Size     Cap     Voltage       100V     1206 1210     ≥ 105 1210     ≥ 105       200V and 250V     1210 1812     > 224 1812     1.5 times of U <sub>R</sub> 1825 2220     ≥ 105 2225     ≥ 105	* Cap change:     C0G(NPO): within ±3% or ±0.3pF whichever is larger     X7R: within ±12.5%     Y5V: within ±30%  * Q/D.F Value:     C0G(NPO): Cap≥30pF :Q≥350;         10pF≤Cap<30pF :Q≥275+2.5C;         Cap<10pF :Q≥200+10C      X7R: ≤3.0%     Y5V: ≤7.5%
		<ul> <li>(2) 250 &lt; U<sub>R</sub> ≤500V: 150% of rated voltage.</li> <li>(3) U<sub>R</sub> &gt; 500V: 120% of rated voltage.</li> <li>(4)1206,NP0 ≥1.5pF: 100% of rated voltage.</li> <li>* Test time: 1000+24/-0 hrs.</li> <li>* Measurement to be made after keeping at room temp. for 24±2 hrs (Class I) or 48±4 hrs (Class II).</li> </ul>	* I.R.: ≥1GΩ or RxC≥50Ω-F whichever is smaller.
	Resistance to Flexure of Substrate	* The middle part of substrate shall be pressurized by means of the pressurizing rod at a rate of about 1mm per second until the deflection becomes 1mm. $\begin{array}{c} 20 \\ \hline \\ $	* No remarkable damage.  * Cap change:  COG(NPO): within ±5.0% or ±0.5pF whichever is larger.  X7R: within ±12.5%  Y5V: within ±30%  (This capacitance change means the change of capacitance under specified flexure of substrate from the capacitance measured before the test.)
	Adhesive Strength of Termination	* Capacitors mounted on a substrate. A force of 5N(≤ 0603) or 10N(> 0603) applied perpendicular to the place of substrate and parallel the line joining the center of terminations for 10±1 second.  5N  PC Board  Capacitor	* No remarkable damage or removal of the terminations.
14.	Vibration Resistance	* Vibration frequency: 10~55 Hz/min.  * Total amplitude: 1.5mm  * Test time: 6 hrs. (Two hrs each in three mutually perpendicular directions.)	* No remarkable damage. * Cap change and Q/D.F.: To meet initial spec.